NSN 5961-01-085-8897

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Inclosure Material:

Metal

Overall Length:

0.450 inches

Overall Diameter:

0.875 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

2.5 base to emitter saturation voltage

Current Rating Per Characteristic:

8.00 amperes source cutoff current and 2.67 amperes source cutoff current

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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